

Supplemental Material to "High-throughput computation of Raman spectra from first principles"

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Contents

Benchmark	1
References	10

List of Tables

S1	Common structures in our database based on the same chemical formula and the mineral name in RRUFF compared to Materials Project tags. The bold RRUFF IDs refer to structures that have also similar lattice parameters.	4
S2	Raman activity of all point groups and irreducible representation (irrep.) based on group theory. True means active and False means inactive	6
S3	Comparison of calculated frequencies and intensities with those obtained from the fits to the experimental spectra shown in Figure 5. Frequency and intensity differences are defined as $\Delta\omega = \omega_{\text{fit}} - \omega_{\text{calc}}$ and $\Delta I = I_{\text{fit}} - I_{\text{calc}}$, where I is the normalized intensity. Std refers to standard deviation.	6

List of Figures

S1	The effect of k-point mesh parameter R_k . (a) and (b) show the unnormalized Raman activity of AlN and Si, respectively, with $R_k = 20$ (blue line), 30 (orange line), 40 (green line) and 60 (red line). (c) and (d) show the effects of different R_k on the maximum intensity of AlN and Si spectra, respectively. (e) and (f) show the effects of different R_k on the average dielectric constant of AlN and Si, respectively.	7
S2	Changes of dielectric constant of (a) PbO and (b) Cd(HO) ₂ in different directions as a function of the displacement step size (0.005–0.04).	8
S3	Comparison of the Raman activity from our workflow and that from vasp_raman code. The spectra from old version of Atomate with incorrect eigenvector normalization is also shown.	9

Benchmark

To benchmark of our approach, we selected four materials with different band gaps and different atomic masses: Si, PbO, AlN, and Cd(HO)₂. We first verified that the standard approach of calculating Raman-tensors for all modes agrees with the Raman-active modes identified using group theory. That is, all the Raman-inactive modes were found to have vanishingly small Raman tensor, although often nonzero due to numerical errors.

Next, we investigated the effect of k-point mesh density on Raman tensors and Raman spectra. We calculated Raman tensors for $R_k = 30, 40$ and 60 and compared the results with the standard value ($R_k = 20$) used in Phonon database. Results from two (out of four) materials are shown in Fig. S1, where, to represent large and small bandgap materials, we selected AlN (4.05 eV) and Si (0.85 eV), respectively. Fig. S1(a,b) shows the unnormalized Raman activity spectra for different R_k , which clearly illustrates that AlN is hardly affected whereas Si experiences significant changes, thus suggesting that R_k should be increased. To better illustrate the magnitude of changes, Fig. S1(c,d) show how the maximum intensity changes with increasing R_k and Fig. S1(e,f) shows the average dielectric constant. In the case of AlN, $R_k = 20$ already yields Raman tensors within 10 % of the converged value and dielectric constant within 1 %. In the case of Si, $R_k = 40$ is required to reach similar accuracy. Based on these results we

decided to use $R_k=40$ for materials with bandgap smaller than 1 eV, $R_k=30$ for materials with bandgap between 1 eV to 2 eV, and $R_k=20$ for materials with a bandgap greater than 2 eV.

In the third step, we investigated the effect of step size by calculating Raman tensors of PbO and Cd(HO)₂ with step sizes of 0.001, 0.02, and 0.04 Å and compared them with those using the standard step size of 0.005 Å. Fig. S2 shows the changes in dielectric constants of PbO and Cd(HO)₂ in different directions and plotted for three-step sizes: 0.005, 0.02, and 0.04 Å. Since dielectric tensor is symmetric ($xy=yx$, $xz=zx$, and $yz=zy$), we only plot the inequivalent components. As shown in Fig. S2, whenever there are pronounced changes in the dielectric constant (corresponding to non-zero components in Raman tensor), the dependence on step size is close to linear. In some cases there is a small parabolic dependence, seen particularly well in the $xy=yx$ component which contains no linear dependence, but these will not affect the Raman tensor since we are using two-point finite-difference stencil. Moreover, in this range of step sizes there is no discernible noise, although some noise could be observed in 0.001 Å results (not shown). Thus, we consider the default value of 0.005 Å a good choice.

As mentioned in the text, there was an error in the normalization of eigenvectors in Atomate. We fixed the normalization error and changed the formulations to match with the vasp_raman code^{1,2}. To verify our approach, we used vasp_raman code to calculate Raman tensors and compared them to Atomate with the fixed and old versions of eigenvector normalization. Fig. S3 shows the Raman activity spectra of MoS₂, WS₂, SrGaSnH, and BaAlSiH. The revised normalization yields activities closely matching with vasp_raman code. The incorrect normalization, on the other hand, tends to lead to overestimation of Raman activities and is particularly severe with modes that have very small Raman activity.

In CRD website (<https://ramandb.oulu.fi>), the total Raman intensity is separated into depolarized ($I_{\perp}$) and polarized ($I_{\parallel}$) components, $I = I_{\perp} + I_{\parallel}$, with

$$\frac{I_{\parallel}}{(\omega_L - \omega_v)^4} \sim \frac{\hbar(n+1)}{30\omega_v} (10G_v^{(0)} + 4G_v^{(2)}) \quad (1)$$

$$\frac{I_{\perp}}{(\omega_L - \omega_v)^4} \sim \frac{\hbar(n+1)}{30\omega_v} (5G_v^{(1)} + 3G_v^{(2)}) \quad (2)$$

where we have taken out the $(\omega_L - \omega_v)^4$ term that depends on the laser wavelength, since (i) this removes the dependence on one external parameter from our spectra, (ii) our calculations are for non-resonant conditions and one needs to be careful to only compare to wavelengths that are far from resonance, and (iii) the dependence on ω_v and thus the changes in the spectra after normalization are usually small. The rotation invariants are^{3,4}

$$G_v^{(0)} = \frac{1}{3} (R_{vxx} + R_{vyy} + R_{vzz})^2 \quad (3)$$

$$G_v^{(1)} = \frac{1}{2} [(R_{vxy} - R_{vyx})^2 + (R_{vzx} - R_{vzx})^2 + (R_{vzy} - R_{vyz})^2] \quad (4)$$

$$G_v^{(2)} = \frac{1}{2} [(R_{vxy} + R_{vyx})^2 + (R_{vzx} + R_{vzx})^2 + (R_{vzy} + R_{vyz})^2] + \frac{1}{3} [(R_{vxx} - R_{vyy})^2 + (R_{vxx} - R_{vzz})^2 + (R_{vzz} - R_{vyy})^2] \quad (5)$$

Mineral name	Formula	mpid	Energy above hull (eV)	RRUFF ID
Billingsleyite	Ag ₇ AsS ₆	mp-15077	0.003	R070350
Sanbornite	BaSi ₂ O ₅	mp-3031	0	R060489
Hardystonite	Ca ₂ ZnSi ₂ O ₇	mp-6227	0.015	R040026
Perovskite	CaTiO ₃	mp-4019	0	R050456
Greenockite	CdS	mp-672	0	R090045
Cobaltite	CoAsS	mp-4627	0.001	R070372
Cobaltite	CoAsS	mp-16363	0.004	R060907
Cuprite	Cu ₂ O	mp-361	0	R050374
Stromeyerite	CuAgS	mp-5014	0.024	R060908
Emplectite	CuBiS ₂	mp-22982	0	R070307

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Table S1 – continued from previous page

Mineral name	Formula	mpid	Energy above hull (eV)	RRUFF ID
Chalcostibite	CuSbS ₂	mp-4468	0	R060262
Pyrite	FeS ₂	mp-226	0.008	R050070
Marcasite	FeS ₂	mp-1522	0	R060882
Langbeinite	K ₂ Mg ₂ (SO ₄) ₃	mp-6299	0	R070285
Aphthitalite	K ₃ Na(SO ₄) ₂	mp-22457	0	R050651
Goldschmidtite	KNbO ₃	mp-7375	0	R190009
Nordite-(La)	Na ₃ SrLaZnSi ₆ O ₁₇	mp-13726	0	R140310
Swedenborgite	NaBe ₄ SbO ₇	mp-8075	0	R060486
Leucophanite	NaCaBeSi ₂ O ₆ F	mp-560721	0	R050004
Neighborite	NaMgF ₃	mp-2955	0	R080108
Cotunnite	PbCl ₂	mp-23291	0.006	R060655
Matlockite	PbClF	mp-22964	0	R140538
Laurite	RuS ₂	mp-2030	0	R110120
Zincite	ZnO	mp-2133	0	R060027
Chrysoberyl	BeAl ₂ O ₄	mp-3081	0	R040073
Wurtzite	ZnS	mp-10281	0.002	R130069
Montroydite	HgO	mp-1224	0	R070235
Quartz	SiO ₂	mp-7000	0.011	R050125
Bromellite	BeO	mp-2542	0	X050194
Litharge	PbO	mp-19921	0.001	R060959
Romarchite	SnO	mp-2097	0	R080006
Anatase	TiO ₂	mp-390	0.006	R060277
Andalusite	Al ₂ SiO ₅	mp-4753	0	R050258
Anglesite	Pb(SO ₄)	mp-3472	0	R040004
Aragonite	CaCO ₃	mp-4626	0.024	R040078
Baryte	Ba(SO ₄)	mp-3164	0	R040036
Brenkite	Ca ₂ CO ₃ F ₂	mp-6246	0.028	R060247
Calcite	CaCO ₃	mp-3953	0	R040070
Cerussite	Pb(CO ₃)	mp-19893	0	R040069
Colquiriite	CaLiAlF ₆	mp-1224	0	R070417
Dolomite	CaMg(CO ₃) ₂	mp-6459	0	R050129
Eitelite	Na ₂ Mg(CO ₃) ₂	mp-6026	0	R110214
Eulytine	Bi ₄ (SiO ₄) ₃	mp-23331	0	R060058
Farringtonite	Mg ₃ (PO ₄) ₂	mp-14396	0	R130127
Geikielite	MgTiO ₃	mp-3771	0	R070479
Glauberite	Na ₂ Ca(SO ₄) ₂	mp-6397	0	R050350
Huntite	CaMg ₃ (CO ₃) ₄	mp-6524	0.004	R040126
Cristobalite	SiO ₂	mp-6945	0.003	R070235
Leiteite	ZnAs ₂ O ₄	mp-29509	0.006	R040011
Lithiophosphate	Li ₃ (PO ₄)	mp-2878	0.001	R100092
Magnesite	Mg(CO ₃)	mp-5348	0	R040114
Nahcolite	NaH(CO ₃)	mp-696396	0	R070237
Witherite	Ba(CO ₃)	mp-5504	0	R040040
Arsenolite	As ₂ O ₃	mp-2184	0.009	R050383
Åkermanite	Ca ₂ MgSi ₂ O ₇	mp-6094	0.023	R061085
Benitoite	BaTi(SiO ₃) ₃	mp-6661	0	R050320
Gahnite	ZnAl ₂ O ₄	mp-2908	0	R070591
Rosiaite	PbSb ₂ O ₆	mp-20727	0	R070384
Xanthoconite	Ag ₃ AsS ₃	mp-561620	0	R070746
Topaz	Al ₂ SiO ₄ F ₂	mp-6280	0	R040121

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Table S1 – continued from previous page

Mineral name	Formula	mpid	Energy above hull (eV)	RRUFF ID
Imiterite	Ag ₂ HgS ₂	mp-9635	0.03	R080014
Acanthite	Ag ₂ S	mp-610517	0.024	R070578
Argyrodite	Ag ₈ GeS ₆	mp-9770	0	R050437
Andalusite	Al ₂ SiO ₅	mp-4934	0.007	R050258
Nitrobarite	Ba(NO ₃) ₂	mp-4396	0	R060622
Barylite	BaBe ₂ Si ₂ O ₇	mp-6383	0	R060620
Barylite	BaBe ₂ Si ₂ O ₇	mp-12797	0	R060606
Guanajuatite	Bi ₂ Se ₃	mp-23164	0.028	R080140
Merwinite	Ca ₃ Mg(SiO ₄) ₂	mp-558209	0.038	R070195
Rankinite	Ca ₃ Si ₂ O ₇	mp-3932	0.009	R140775
Hurlbutite	CaBe ₂ (PO ₄) ₂	mp-6772	0	R090048
Rynersonite	CaTa ₂ O ₆	mp-18229	0	R080064
Arsenopyrite	FeAsS	mp-561511	0	R050071
Gudmundite	FeSbS	mp-27904	0	R060741
Cinnabar	HgS	mp-634	0.004	R070532
Cinnabar	HgS	mp-9252	0.004	R070532
Kalsilite	KAlSiO ₄	mp-8355	0.002	R060801
Kalsilite	KAlSiO ₄	mp-9480	0.002	R060030
Avogadrite	KBF ₄	mp-4929	0	R110062
Kotoite	Mg ₃ (BO ₃) ₂	mp-5005	0	R060940
Natrosilite	Na ₂ Si ₂ O ₅	mp-3193	0	R060855
Molybdomenite	PbSeO ₃	mp-20716	0	R140388
Valentinite	Sb ₂ O ₃	mp-2136	0	R120096
Stibnite	Sb ₂ S ₃	mp-2809	0	R120137
Moissanite	SiC	mp-7631	0	R150016
Tellurite	TeO ₂	mp-2125	0	R070606
Rutile	TiO ₂	mp-2657	0.037	R060745, R120008
Brookite	TiO ₂	mp-1840	0.02	R050363, R050591, R130225
Lorándite	TlAsS ₂	mp-4988	0	R110055
Tungstenite	WS ₂	mp-224	0	R070616
Waimirite-(Y)	YF ₃	mp-2416	0	R130714
Reinerite	Zn ₃ (AsO ₃) ₂	mp-27580	0	R080132
Baddeleyite	ZrO ₂	mp-2858	0	R100171

Table S1. Common structures in our database based on the same chemical formula and the mineral name in RRUFF compared to Materials Project tags. The bold RRUFF IDs refer to structures that have also similar lattice parameters.

Point group	Irrep. label	Raman Activity	Point group	Irrep. label	Raman Activity
C ₁ (1)	A	True	C ₆ (6)	A	True
C _i (-1)	A _g	True		B	False
	A _u	False		E ₁	True
C ₂ (2)	A	True		E ₂	True
	B	True	C _{3h} (-6)	A'	True
C _{1v} = C _s = C _{1h} (m)	A'	True		E'	True
	A''	True		A''	False
C _{2h} (2/m)	A _g	True		E''	True
	B _g	True	C _{6h} (6/m)	A _g	True
	A _u	False		B _g	False
	B _u	False		E _{1g}	True

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Table S2 – continued from previous page

Point group	Irrep. label	Raman Activity	Point group	Irrep. label	Raman Activity
D ₂ (222)	A	True	D ₆ (622)	E _{2g}	True
	B ₁	True		A _u	False
	B ₂	True		B _u	False
C _{2v} (mm2)	B ₃	True		E _{1u}	False
	A ₁	True		E _{2u}	False
	A ₂	True		A ₁	True
D _{2h} (mmm)	B ₁	True		A ₂	False
	B ₂	True		B ₁	False
	A _g	True		B ₂	False
	B _{1g}	True		E ₁	True
	B _{2g}	True		E ₂	True
	B _{3g}	True	C _{6v} (6mm)	A ₁	True
	A _u	False		A ₂	False
	B _{1u}	False		B ₁	False
	B _{2u}	False		B ₂	False
	B _{3u}	False		E ₁	True
	A	True		E ₂	True
C ₄ (4)	B	True	D _{3h} (-6m2)	A' ₁	True
	E	True		A' ₂	False
S ₄ (-4)	A	True		E'	True
	B	True		A'' ₁	False
	E	True		A'' ₂	False
C _{4h} (4/m)	A _g	True		E''	True
	B _g	True	D _{6h} (6/mmm)	A _{1g}	True
	E _g	True		A _{2g}	False
	A _u	False		B _{1g}	False
	B _u	False		B _{2g}	False
D ₄ (422)	E _u	False		E _{1g}	True
	A ₁	True		E _{2g}	True
	A ₂	False		A _{1u}	False
	B ₁	True		A _{2u}	False
	B ₂	True		B _{1u}	False
	E	True		B _{2u}	False
C _{4v} (4mm)	A ₁	True	T (23)	E _{1u}	False
	A ₂	False		E _{2u}	False
	B ₁	True		A	True
	B ₂	True		E	True
	E	True	T _h (m-3)	T	True
D _{2d} (-42m)	A ₁	True		A _g	True
	A ₂	False		A _u	False
	B ₁	True		E _g	True
	B ₂	True		E _u	False
	E	True		T _g	True
D _{4h} (4/mmm)	A _{1g}	True		T _u	False
	A _{2g}	False	O (432)	A ₁	True
	B _{1g}	True		A ₂	False
	B _{2g}	True		E	True
	E _g	True		T ₁	False
	A _{1u}	False		T ₂	True
	A _{2u}	False	T _d (-43m)	A ₁	True
	B _{1u}	False		A ₂	False
	B _{2u}	False		E	True

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Table S2 – continued from previous page

Point group	Irrep. label	Raman Activity	Point group	Irrep. label	Raman Activity
C ₃ (3)	E _u	False	O _h (m-3m)	T ₁	False
	A	True		T ₂	True
	E	True		A _{1g}	True
S ₆ (-3)	A _g	True		A _{2g}	False
	E _g	True		E _g	True
	A _u	False		T _{1g}	False
D ₃ (32)	E _u	False		T _{2g}	True
	A ₁	True		A _{1u}	False
	A ₂	False		A _{2u}	False
C _{3v} (3m)	E	True		E _u	False
	A ₁	True		T _{1u}	False
	A ₂	False		T _{2u}	False
D _{3d} (-3m)	E	True			
	A _{1g}	True			
	A _{2g}	False			
	E _g	True			
	A _{1u}	False			
	A _{2u}	False			
	E _u	False			

Table S2. Raman activity of all point groups and irreducible representation (irrep.) based on group theory. True means active and False means inactive

Formula	Avg[$\Delta\omega$] (cm ⁻¹)	Avg[ΔI] (a.u.)	Std(Freq) (cm ⁻¹)	Std(I) (a.u.)
HgO	3.52	-0.02	11.35	0.02
SiO ₂	18.54	-0.02	5.95	0.03
MgCO ₃	6.67	-0.05	12.26	0.07
CaMg(CO ₃) ₂	2.61	0.04	14.78	0.15

Table S3. Comparison of calculated frequencies and intensities with those obtained from the fits to the experimental spectra shown in Figure 5. Frequency and intensity differences are defined as $\Delta\omega = \omega_{\text{fit}} - \omega_{\text{calc}}$ and $\Delta I = I_{\text{fit}} - I_{\text{calc}}$, where I is the normalized intensity. Std refers to standard deviation.

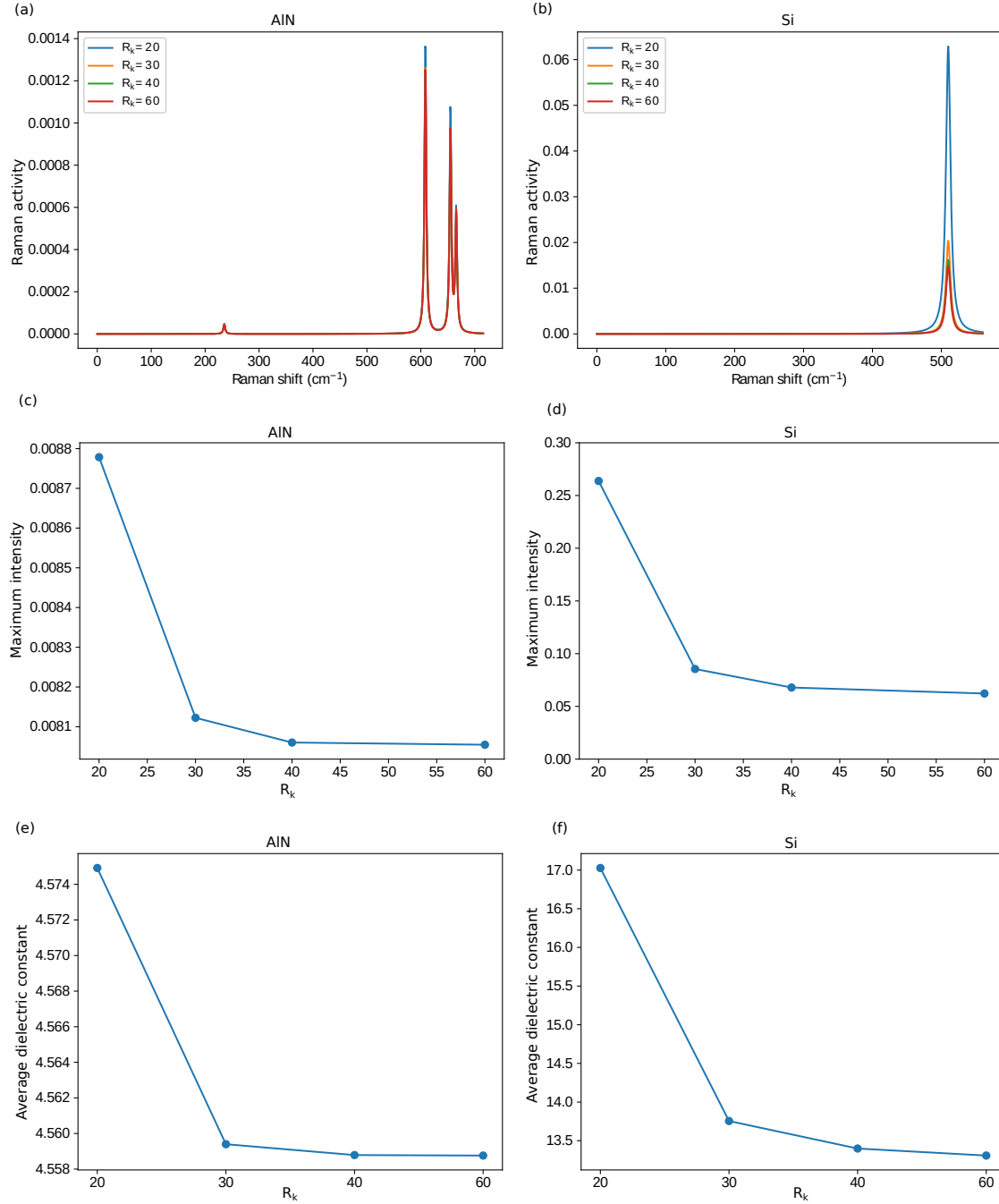


Figure S1. The effect of k-point mesh parameter R_k . (a) and (b) show the unnormalized Raman activity of AlN and Si, respectively, with $R_k = 20$ (blue line), 30 (orange line), 40 (green line) and 60 (red line). (c) and (d) show the effects of different R_k on the maximum intensity of AlN and Si spectra, respectively. (e) and (f) show the effects of different R_k on the average dielectric constant of AlN and Si, respectively.

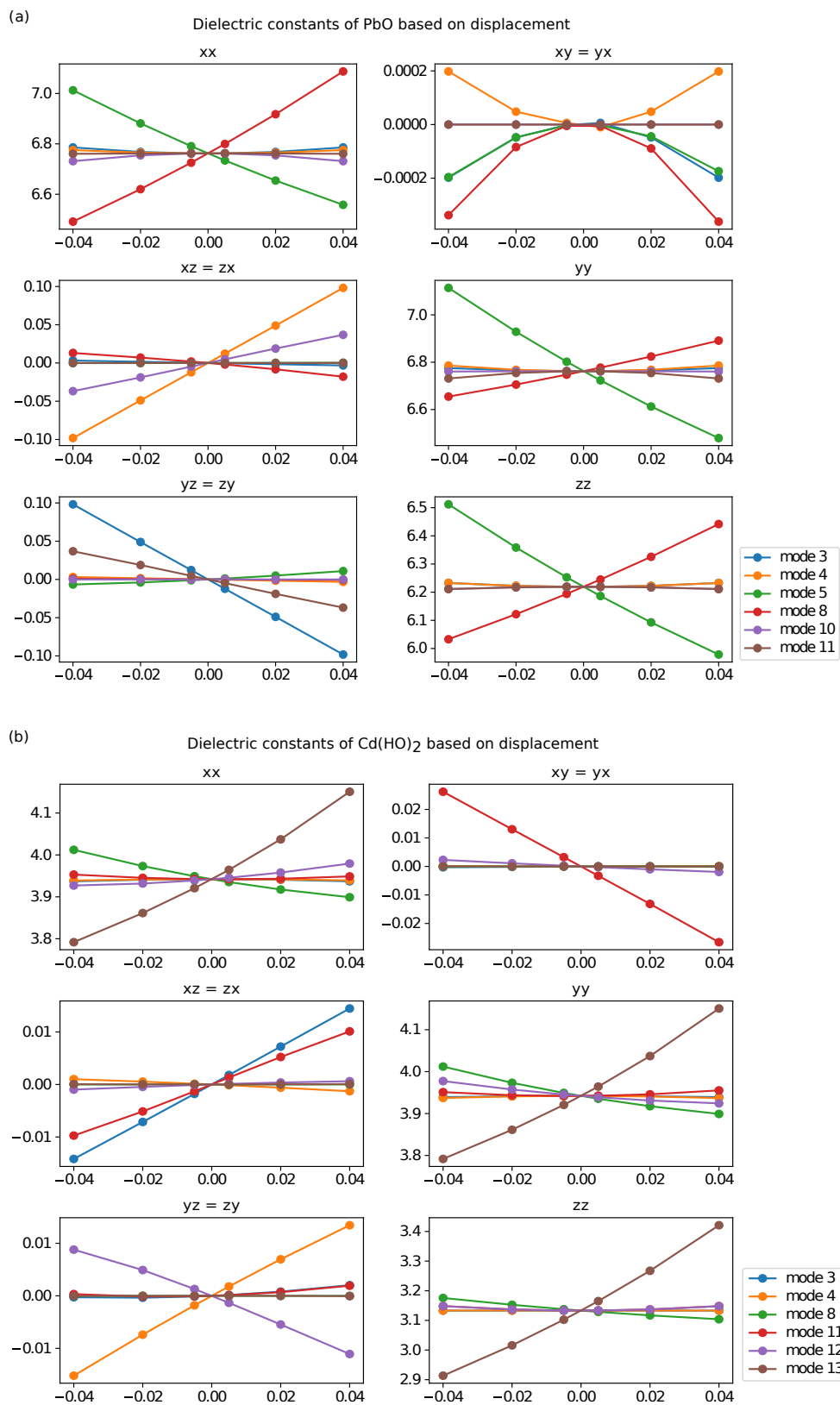


Figure S2. Changes of dielectric constant of (a) PbO and (b) Cd(HO)₂ in different directions as a function of the displacement step size (0.005–0.04).

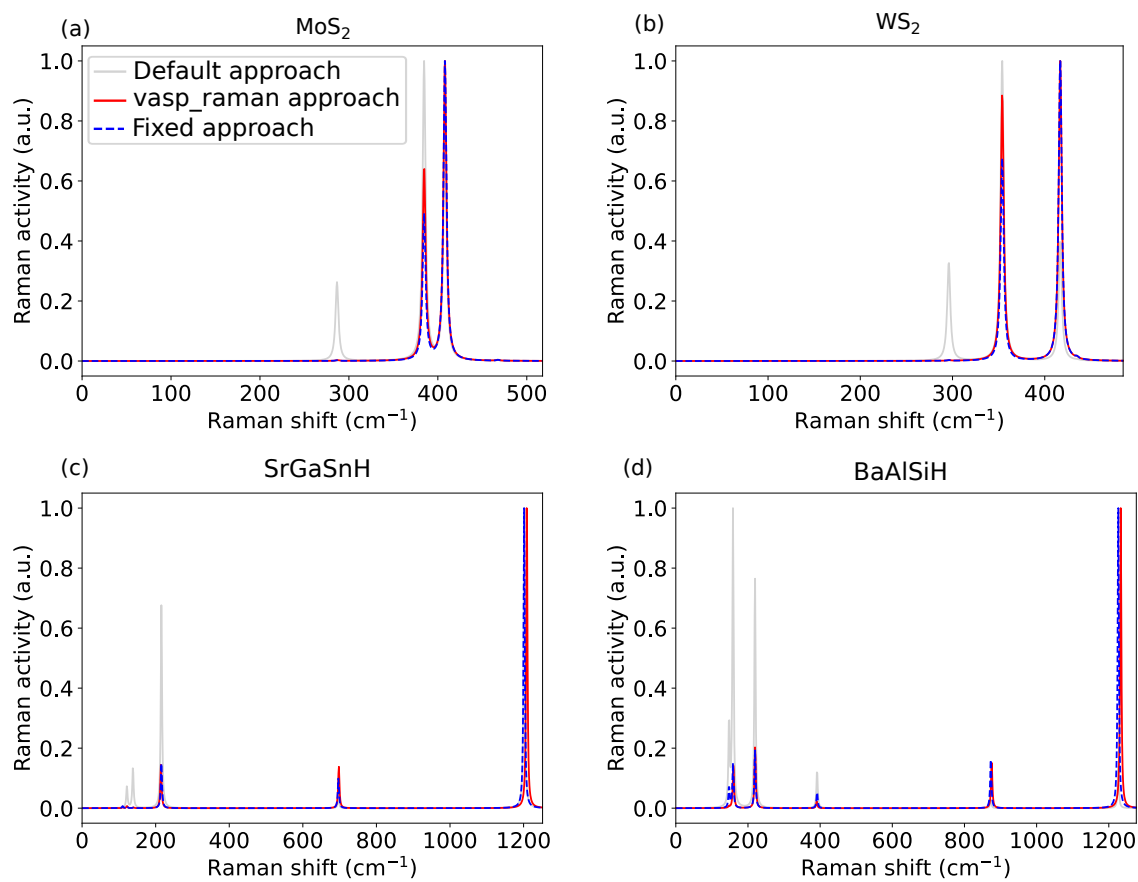


Figure S3. Comparison of the Raman activity from our workflow and that from vasp_raman code. The spectra from old version of Atomate with incorrect eigenvector normalization is also shown.

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